

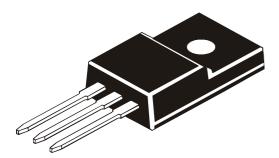
Continental Device India Limited

An IS/ISO 9002 and IECQ Certified Manufacturer





PNP SILICON EPITAXIAL POWER TRANSISTOR



CFB1370 (9AW) TO-220FP

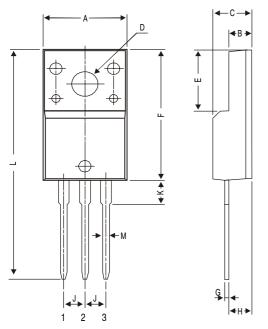
Designed For AF Power Amplifier.

ABSOLUTE MAXIMUM RATINGS(Ta=25deg C)

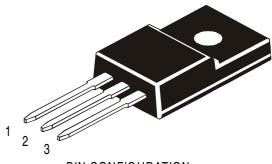
DESCRIPTION	SYMBOL	VALUE	UNIT
Collector -Base Voltage	VCBO	60	V
Collector -Emitter Voltage	VCEO	60	V
Emitter- Base Voltage	VEBO	5.0	V
Collector Current	IC	3.0	Α
Peak	ICP	6.0	Α
Power Dissipation @ Ta=25 deg C	PC	2.0	W
Power Dissipation @ Tc=25 deg C		30	W
Junction Temperature	Tj	150	deg C
Storage Temperature Range	Tstg	-55 to +150	deg C

ELECTRICAL CHARACTERISTICS (Ta=25 DESCRIPTION	SYMBOL		MIN	TYP	MAX	UNIT
Collector Emitter Voltage	VCEO	IC=1mA, IB=0	60	- 111	IVIAA	\/ \/
Collector Base Voltage	VCBO	IC=50uA, IE=0	60	_	_	V
Emitter Base Voltage	VEBO	IE=50uA,IC=0	5.0	_	_	V
Collector Cut off Current	ICBO	/CB=60V, IE=0		_	10	uA
Emitter Cut off Current	IEBO	VEB=4V,IC=0	_	-	10	uA
Collector Emitter Saturation Voltage	VCE(Sat)	,	-	-	1.5	V
Base Emitter Saturation Voltage	VBE(Sat)	IC=2A, IB=0.2A	-	-	1.5	V
DC Current Gain	hFE `´	IC=0.5A, VCE=5V	60	-	320	
Dynamic Characteristics						
Transition Frequency	ft	VCE=5V,IC=0.5A,	-	15	-	MHz
		f=5MHz				
Collector Output Capacitance	Cob	VCB=10V, IE=0	-	80	-	pF
		f=1MHz				
hFE CLASSIFICATION:-		D: 60 -120;	E: 100 -200 F: 160		60 -320	
MARKING:		CFB	CI	FB	С	FB
		1370	1370		1370	
		D	I	E		F

TO-220FP (Fully Isolated) Plastic Package



	DIM	MIN	MAX	
All diminsions in mm.	Α	9.96	10.36	
	В	2.60	3.00	
	С	4.50	4.90	
	D	3.10	3.30	
	E	7.90	8.20	
	F	16.87	17.27	
	G	0.45	0.50	
	Н	2.56	2.96	
	J	2.34	2.74	
	K	_	3.08	
	L	_	30.05	
	М	_	0.80	



PIN CONFIGURATION

- 1. BASE
- 2. COLLECTOR
- 3. EMITTER

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
T0-220 / FP	200 pcs/polybag 50 pcs/tube		3" x 7.5" x 7.5" 3.5" x 3.7" x 21.5"		17" x 15" x 13.5" 19" x 19" x 19"	16.0K 10.0K	36 kgs 29 kgs

Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of

Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.
Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290
e-mail sales@cdil.com www.cdil.com